

RJQ6015DPM

600V - 18A - IGBT and Diode

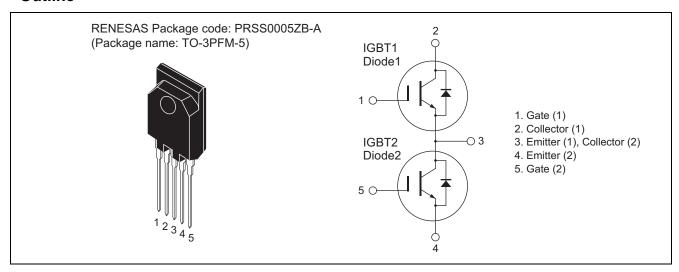
Application: Inverter

R07DS0848EJ0100 Rev.1.00 Jul 27, 2012

Features

- Short circuit withstand time (5 µs typ.)
- Low collector to emitter saturation voltage $V_{CE(sat)} = 1.6 \text{ V}$ typ. (at $I_C = 37 \text{ A}$, $V_{GE} = 15 \text{ V}$, $Ta = 25^{\circ}\text{C}$)
- Built in fast recovery diode (100 ns typ.) in one package
- Trench gate and thin wafer technology
- High speed switching t_f = 40 ns typ. (at V_{CC} = 300 V, V_{GE} = 15 V, I_C = 37 A, Rg = 5 Ω , Ta = 25°C, inductive load)

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item		Symbol	Ratings	Unit
Collector to emitter voltage/diode reverse voltage		V _{CES} /V _R	600	V
Gate to emitter voltage		V _{GES}	±30	V
Collector current	Tc = 25°C	I _C Note1	37	Α
	Tc = 100°C	I _C Note1	18	Α
Collector peak current		I _{C(peak)} Note3	150	Α
Collector to emitter diode forward current		I _{DF} Note1	20	А
Collector to emitter diode forward peak current		I _{DF(peak)} Note3	150	Α
Collector dissipation		P _C Note2	50	W
Junction to case thermal resistance (IGBT)		θј-с	2.5	°C/W
Junction to case thermal resistance (Diode)		θj-cd	4.5	°C/W
Junction temperature		Tj	150	°C
Storage temperature		Tstg	-55 to +150	°C

Notes: 1. Limited by Tj max.

- 2. Value at Tc = 25°C
- 3. Pulse width limited by maximum safe operating area.

Electrical Characteristics

IGBT1, IGBT2 (Ta = 25°C)

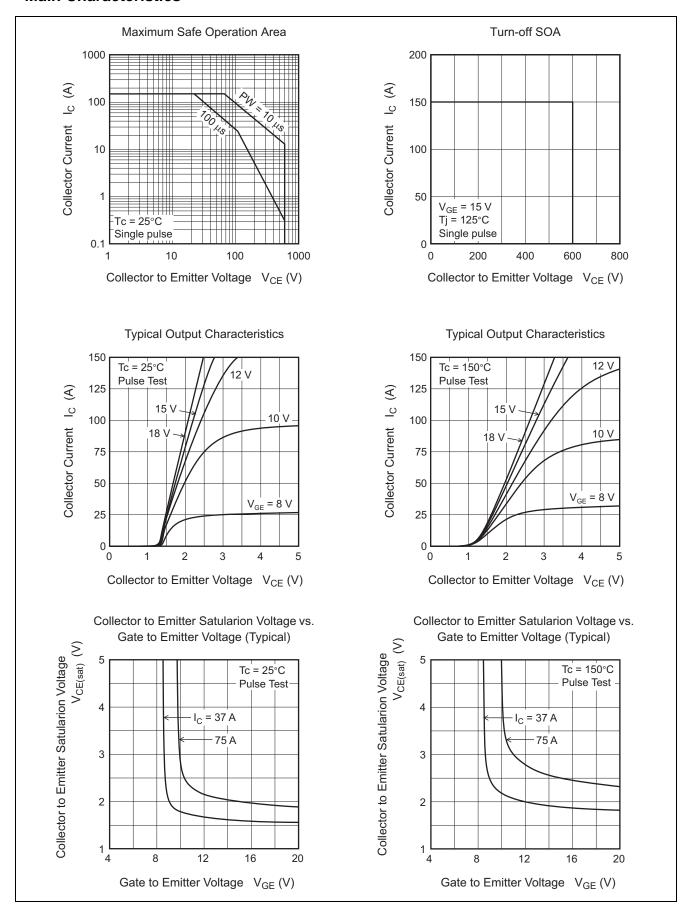
Item	Symbol	Min	Тур	Max	Unit	Test Conditions	
Collector to emitter breakdown voltage/Diode reverse voltage	V _{BR(CES)} /V _R	600	_	_	V	$I_C = 10 \mu A, V_{GE} = 0$	
Zero gate voltage collector current /Diode reverse current	I _{CES} /I _R	_	_	5	μΑ	V _{CE} = 600 V, V _{GE} = 0	
Gate to emitter leak current	I _{GES}	_	_	±1	μΑ	$V_{GE} = \pm 30 \text{ V}, V_{CE} = 0$	
Gate to emitter cutoff voltage	$V_{GE(off)}$	4.0	_	6.0	V	$V_{CE} = 10 \text{ V}, I_{C} = 1 \text{ mA}$	
Collector to emitter saturation	V _{CE(sat)}	_	1.6	2.2	V	$I_C = 37 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note4}}$	
voltage	V _{CE(sat)}	_	2.0	_	V	$I_C = 75 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note4}}$	
Input capacitance	Cies	_	1900	_	pF	V _{CE} = 25 V	
Output capacitance	Coes	_	120	_	pF	$V_{GE} = 0$	
Reveres transfer capacitance	Cres	_	50	_	pF	f = 1 MHz	
Total gate charge	Qg	_	78	_	nC	V _{GE} = 15 V V _{CE} = 300 V I _C = 37 A	
Gate to emitter charge	Qge	_	12	_	nC		
Gate to collector charge	Qgc	_	32	_	nC		
Turn-on delay time	t _{d(on)}	_	50	_	ns	V _{CC} = 300 V	
Rise time	t _r	_	40	_	ns	V _{GE} = 15 V	
Turn-off delay time	t _{d(off)}	_	135	_	ns	$I_C = 37 \text{ A}$	
Fall time	t _f	_	40	_	ns	Rg = 5 Ω Inductive load	
Turn-on energy	Eon	_	0.65	_	mJ		
Turn-off energy	E _{off}	_	0.4	_	mJ		
Total switching energy	E _{total}		1.05		mJ		
Short circuit withstand time	t _{sc}	3.0	5.0	_	μS	$V_{CC} \le 360 \text{ V}, V_{GE} = 15 \text{ V}$	

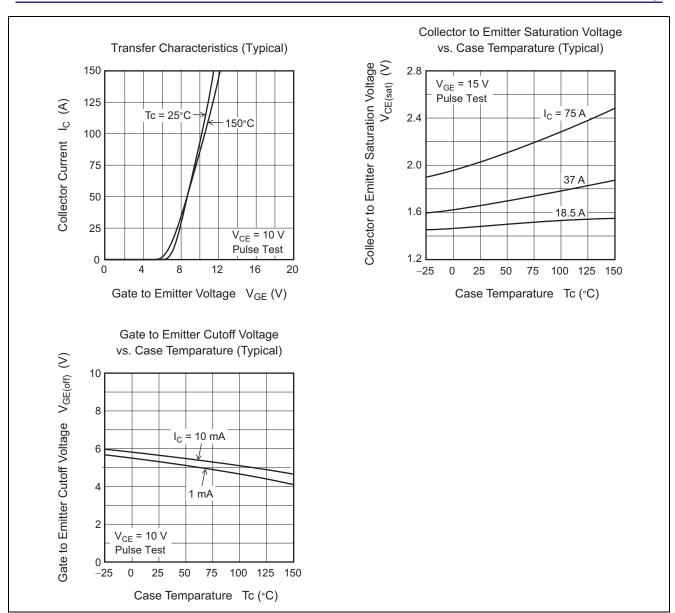
Notes: 4. Pulse test

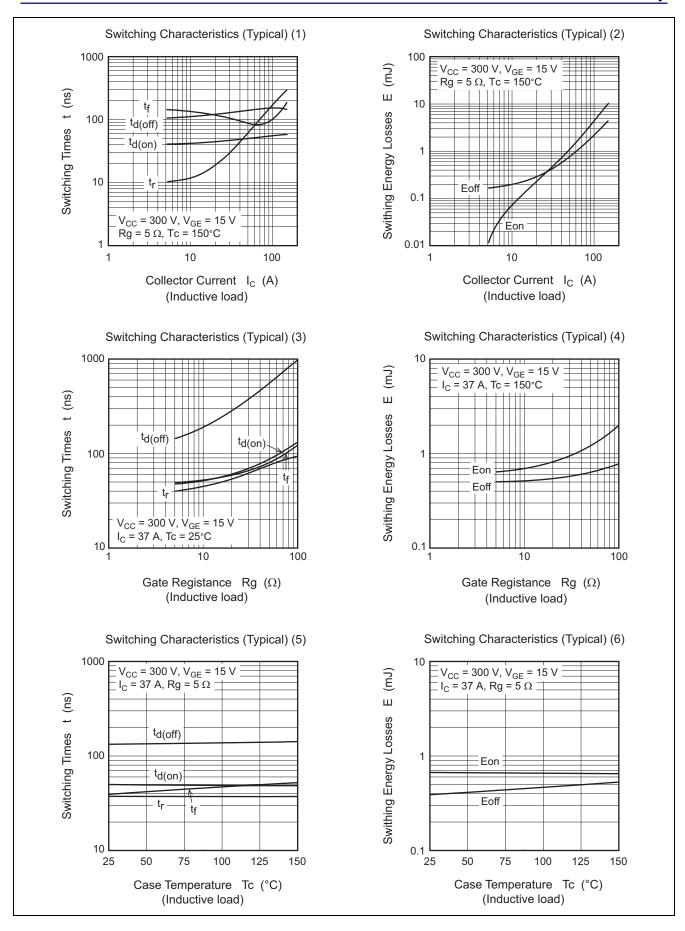
Diode1, Diode2 $(Ta = 25^{\circ}C)$

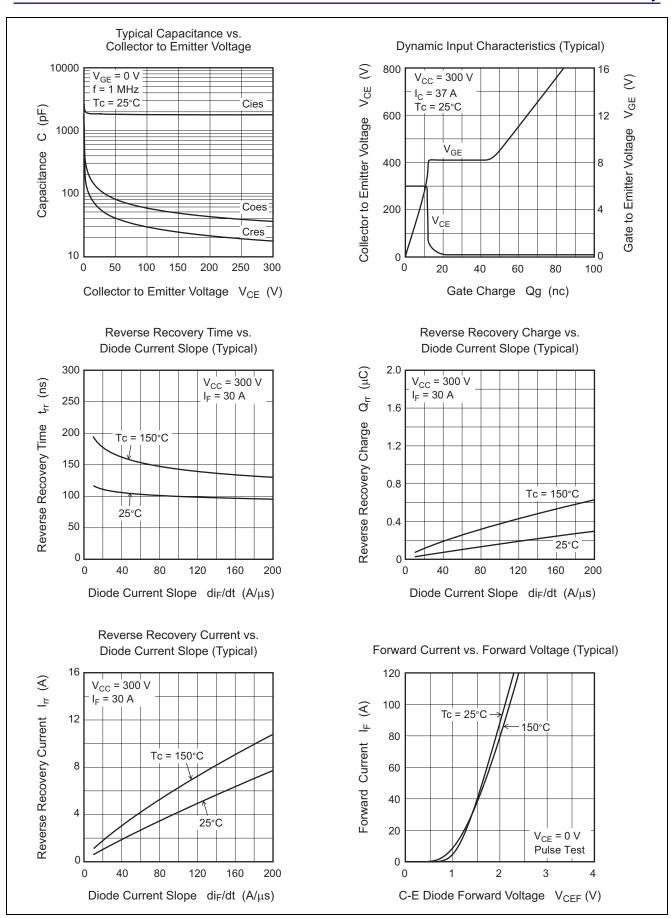
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Forward voltage	V_{F}	_	1.4	1.9	V	I _F = 30 A
Reverse current	I _R	_	_	1	μΑ	V _R = 600 V
Reverse recovery Time	t _{rr}	_	100	_	ns	I _F = 30 A
FRD reverse recovery charge	Q _{rr}	_	0.18	_	μС	di/dt = 100 A/μs
FRD peak reverse recovery current	I _{rr}	_	4.2	_	Α	

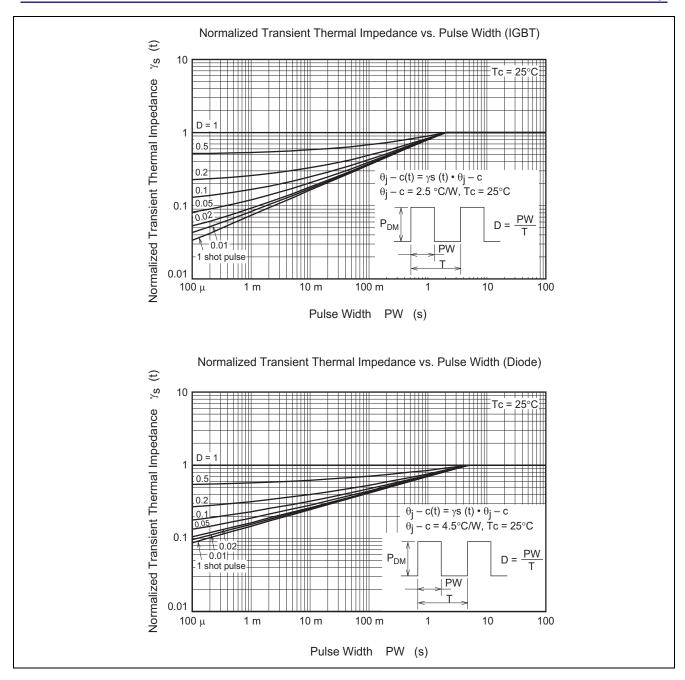
Main Characteristics

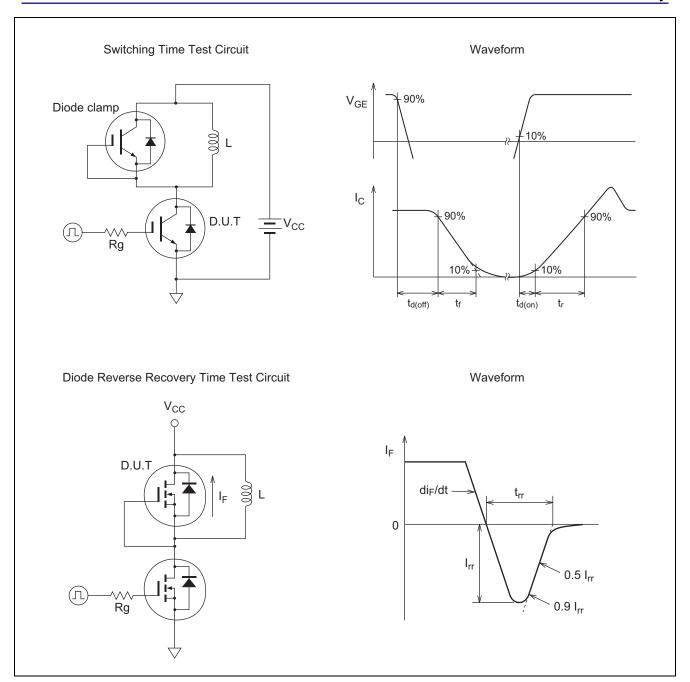




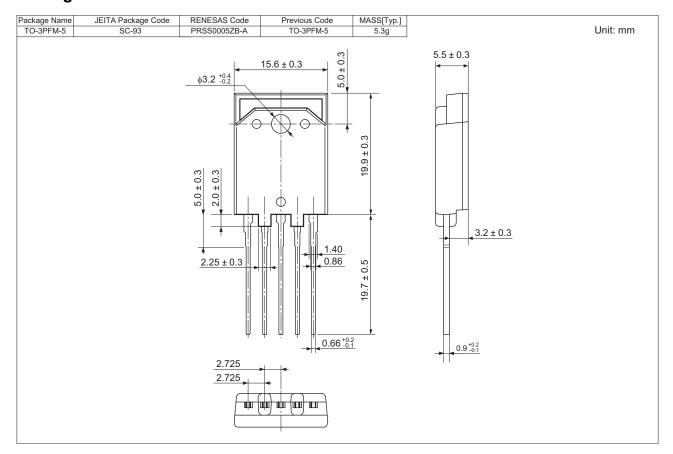








Package Dimensions



Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJQ6015DPM-00#T0	360 pcs	Box (tube)

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Renesas Electronics America Inc. 2880 Scott Boulevard Santa Clara, CA 95050-2554, U.S.A. Tel: +1-408-588-6000, Fax: +1-408-588-6130

Renesas Electronics Canada Limited 1101 Nicholson Road, Newmarket, Ontario L3Y 9C3, Canada Tel: +1-905-898-5441, Fax: +1-905-898-3220

Renesas Electronics Europe Limited
Dukes Meadow, Milliboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K
Tel: +44-1628-585-100, Fax: +44-1628-585-900

Renesas Electronics Europe GmbH

Arcadiastrasse 10, 40472 Düsseldorf, Germany Tel: +49-211-65030, Fax: +49-211-6503-1327

Renesas Electronics (China) Co., Ltd. 7th Floor, Quantum Plaza, No.27 ZhiChunLu Ha Tel: +86-10-8235-1155, Fax: +86-10-8235-7679 i. nunLu Haidian District. Beiiing 100083. P.R.China

Renesas Electronics (Shanghai) Co., Ltd.
Unit 204, 205, AZIA Center, No.1233 Lujiazui Ring Rd., Pudong District, Shanghai 200120, China Tel: +86-21-5877-1818, Fax: +86-21-6887-7858 / -7898

Renesas Electronics Hong Kong Limited
Unit 1601-1613, 16/F., Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong
Tel: +852-2868-9318, Fax: +852 2869-9022/9044

Renesas Electronics Taiwan Co., Ltd. 13F, No. 363, Fu Shing North Road, Taipei, Taiwan Tel: +886-2-8175-9600, Fax: +886 2-8175-9670

Renesas Electronics Singapore Pte. Ltd. 1 harbourFront Avenue, #06-10, keppel Bay Tower, Singapore 098632 Tel: +65-6213-0200, Fax: +65-6278-8001

Renesas Electronics Malaysia Sdn.Bhd.

тинивова специонизь манаузна эцп. Бли.
Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No. 18, Jln Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia Tel: +60-3-7955-9390, Fax: +60-3-7955-9510

Renesas Electronics Korea Co., Ltd. 11F., Samik Lavied' or Bldg., 720-2 Yeoksam-Dong, Kangnam-Ku, Seoul 135-080, Korea Tel: 482-2558-3737, Fax: 482-2558-5141

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